

“CdSe quantum dot formation: alternative paths to relaxation of a strained CdSe layer and influence of the capping conditions”. Robin I-C, Aichele T, Bougerol C, André R, Tatarenko S, Bellet-Amalric E, van Daele B, Van Tendeloo G, Nanotechnology **18**, 265701 (2007). <http://doi.org/10.1088/0957-4484/18/26/265701>